INTEGRATED CIRCUITS

DATA SHEET

74ABT16244A 74ABTH16244A

16-bit buffer/line driver (3-State)

Product specification Supersedes data of 1998 Feb 25 IC23 Data Handbook





16-bit buffer/line driver (3-State)

74ABT16244A 74ABTH16244A

FEATURES

- 16-bit bus interface
- Multiple V_{CC} and GND pins minimize switching noise
- Power-up 3-State
- 3-State buffers
- Output capability: +64 mA/-32mA
- Live insertion/extraction permitted
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000 V per MIL STD 883 Method 3015 and 200 V per Machine Model
- 74ABTH16244A incorporates bus hold data inputs which eliminate the need for external pull up resistors to hold unused inputs
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs

DESCRIPTION

The 74ABT16244A high-performance BiCMOS device combines low static and dynamic power dissipation with high speed and high output drive.

The 74ABT16244A device is a 16-bit buffer that is ideal for driving bus lines. The device features four Output Enables (10E, 20E, 30E, 40E), each controlling four of the 3-State outputs.

Two options are available, 74ABT16244A which does not have the bus hold feature and 74ABTH16244A which incorporates the bus hold feature.

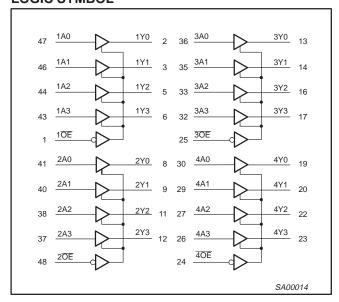
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25°C; GND = 0V	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay nAx to nYx	$C_L = 50pF; V_{CC} = 5V$	1.7 2.1	ns
C _{IN}	Input capacitance	$V_I = 0V \text{ or } V_{CC}$	4	pF
C _{OUT}	Output capacitance	$V_O = 0V$ or V_{CC} ; 3-State	7	pF
I _{CCZ}	Quiescent supply current	Outputs disabled; V _{CC} = 5.5V	450	μΑ
I _{CCL}	Quiescent supply current	Outputs low; $V_{CC} = 5.5V$	10	mA

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
48-Pin Plastic SSOP Type III	-40°C to +85°C	74ABT16244A DL	BT16244A DL	SOT370-1
48-Pin Plastic TSSOP Type II	-40°C to +85°C	74ABT16244A DGG	BT16244A DGG	SOT362-1
48-Pin Plastic SSOP Type III	-40°C to +85°C	74ABH16244A DL	BH16244A DL	SOT370-1
48-Pin Plastic TSSOP Type II	-40°C to +85°C	74ABH16244A DGG	BH16244A DGG	SOT362-1

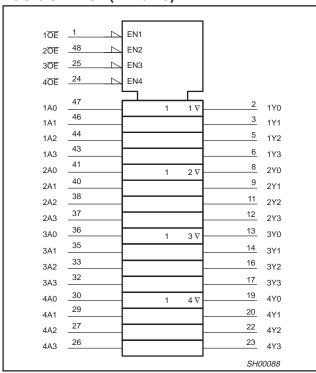
LOGIC SYMBOL



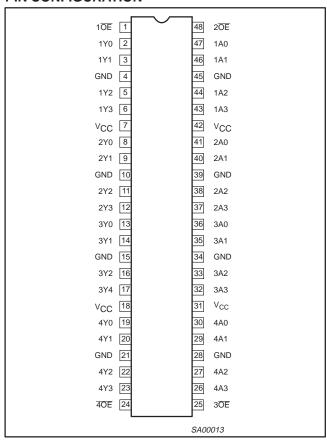
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LOGIC SYMBOL (IEEE/IEC)



PIN CONFIGURATION



PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION		
47, 46, 44, 43 41, 40, 38, 37 36, 35, 33, 32 30, 29, 27, 26	1A0 – 1A3, 2A0 – 2A3, 3A0 – 3A3, 4A0 – 4A3	Data inputs		
2, 3, 5, 6 8, 9, 11, 12 13, 14, 16, 17 19, 20, 22, 23	1Y0 - 1Y3, 2Y0 - 2Y3, 3Y0 - 3Y3, 4Y0 - 4Y3	Data outputs		
1, 48 25, 24	1 <u>OE</u> , 2 <u>OE</u> , 3 <u>OE</u> , 4 <u>OE</u>	Output enables		
4, 10, 15, 21 28, 34, 39, 45	GND	Ground (0V)		
7, 18, 31, 42	V _{CC}	Positive supply voltage		

FUNCTION TABLE

INP	OUTPUTS	
nOE	nAx	nYx
L	L	L
L	Н	Н
Н	Х	Z

H = High voltage level

L = Low voltage level

X = Don't care

Z = High impedance "off" state

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ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +7.0	V
I _{IK}	DC input diode current	V _I < 0	-18	mA
V _I	DC input voltage ³		-1.2 to +7.0	V
I _{OK}	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	output in Off or High state	-0.5 to +5.5	V
	DC output ourrent	output in Low state	128	mA
Гоит	DC output current	output in High state	-64	IIIA
T _{stg}	Storage temperature range		-65 to 150	°C

NOTES:

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	UNIT	
STWIBUL	PARAMETER	MIN	MAX	UNII
V _{CC}	DC supply voltage	4.5	5.5	V
VI	Input voltage	0	V _{CC}	V
V _{IH}	High-level input voltage	2.0		V
V _{IL}	Low-level input voltage		0.8	V
I _{OH}	High-level output current		-32	mA
I _{OL}	Low-level output current		64	mA
Δt/Δν	Input transition rise or fall rate	0	10	ns/V
T _{amb}	Operating free-air temperature range	-40	+85	°C

Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the
device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to
absolute-maximum-rated conditions for extended periods may affect device reliability.

^{2.} The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

^{3.} The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

16-bit buffer/line driver (3-State)

DC ELECTRICAL CHARACTERISTICS

				LIMITS						
SYMBOL	PARAMETER	TEST CO	TEST CONDITIONS			i°C	T _{amb} =	UNIT		
				Min	Тур	Max	Min	Max	1	
V _{IK}	Input clamp voltage	$V_{CC} = 4.5V; I_{IK} = -18m$	nA		-0.9	-1.2		-1.2	V	
		V_{CC} = 4.5V; I_{OH} = -3mA; V_I = V_{IL} or V_{IH}		2.5	2.9		2.5			
V_{OH}	High-level output voltage	$V_{CC} = 5.0V; I_{OH} = -3m$	A; $V_I = V_{IL}$ or V_{IH}	3.0	3.4		3.0		V	
		$V_{CC} = 4.5V; I_{OH} = -32r$	$mA; V_I = V_{IL} \text{ or } V_{IH}$	2.0	2.4		2.0			
V_{OL}	Low-level output voltage	$V_{CC} = 4.5V; I_{OL} = 64m.$	A; $V_I = V_{IL}$ or V_{IH}		0.42	0.55		0.55	V	
II	Input leakage current	$V_{CC} = 5.5V$; $V_I = GND$	or 5.5V		±0.01	±1.0		±1.0	μΑ	
	Input leakage current	$V_{CC} = 5.5V; V_I = V_{CC}$ or GND	Control pins		±0.01	±1		±1		
I _I	74ABTH16244A	$V_{CC} = 5.5V$; $V_I = V_{CC}$	Data Pins		0.01	1		1	μΑ	
		$V_{CC} = 5.5V; V_I = 0$	Data Filis		-2	-3		- 5		
	Due Held sument A innuteA	V _{CC} = 4.5V; V _I = 0.8V		50			50			
I_{HOLD}	Bus Hold current A inputs ⁴ 74ABTH16244A	$V_{CC} = 4.5V; V_I = 2.0V$	-75			-75		μΑ		
		$V_{CC} = 5.5V$; $V_I = 0$ to $5.5V$		±500						
I _{OFF}	Power-off leakage current	$V_{CC} = 0.0V$; V_O or $V_I \le 4.5V$			±5.0	±100		±100	μΑ	
I_{PU}/I_{PD}	Power-up/down 3-State output current	$V_{\underline{CC}} = 2.0V; V_{\underline{O}} = 0.5V$ $V_{\underline{OE}} = V_{\underline{CC}}$; $V_I = GND \text{ or } V_{CC}$;		±5.0	±50		±50	μА	
I _{OZH}	3-State output High current	$V_{CC} = 5.5V; V_{O} = 5.5V$	$V_{I} = V_{IL} \text{ or } V_{IH}$		0.1	10		10	μΑ	
I _{OZL}	3-State output Low current	$V_{CC} = 5.5V; V_{O} = 0.0V$	$V_{I} = V_{IL} \text{ or } V_{IH}$		-0.1	-10		-10	μΑ	
I _{CEX}	Output High leakage current	$V_{CC} = 5.5V; V_{O} = 5.5V$	$V_I = GND \text{ or } V_{CC}$		5.0	50		50	μΑ	
I _O	Output current ¹	$V_{CC} = 5.5V; V_{O} = 2.5V$		-50	-100	-180	-50	-180	mA	
I _{CCH}		V_{CC} = 5.5V; Outputs Hi	gh, $V_I = GND$ or V_{CC}		0.45	1.0		1.0	mA	
I _{CCL}	Quiescent supply current ³	V_{CC} = 5.5V; Outputs Lo	ow, $V_I = GND$ or V_{CC}		10	19		19	mA	
I _{CCZ}		$V_{CC} = 5.5V$; Outputs 3- $V_{I} = GND \text{ or } V_{CC}$	State;		0.45	1.0		1.0	μА	
		Outputs enabled, one data input at 3.4V, other inputs at V_{CC} or GND; $V_{CC} = 5.5V$			100	250		250		
ΔI_{CC}	Additional supply current per input pin ^{2, 3}	Outputs disabled, one other inputs at V _{CC} or 0		100	250		250	μΑ		
	bar b	Control pins, outputs di input at 3.4V, other input V _{CC} = 5.5V		100	250		250			

- 1. Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

- This is the increase in supply current for each input at 3.4V.
 This data sheet limit may vary among suppliers.
 This is the bus hold overdrive current required to force the input to the opposite logic state.

16-bit buffer/line driver (3-State)

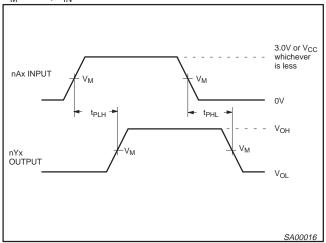
AC CHARACTERISTICS

GND = 0V; t_R = t_F = 2.5ns; C_L = 50pF, R_L = 500 Ω

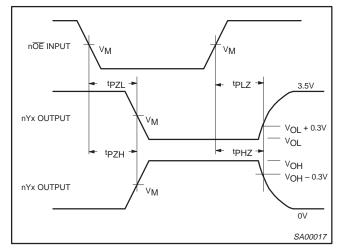
			LIMITS					
SYMBOL	PARAMETER	WAVEFORM	Ţ	. _{amb} = +25°0 V _{CC} = +5.0V	Ç	T _{amb} = -40° V _{CC} = +5.	°C to +85°C .0V ±0.5V	UNIT
			MIN	TYP	MAX	MIN	MAX	
t _{PLH} t _{PHL}	Propagation delay nAx to nYx	1	1.1 1.3	1.7 2.1	2.6 2.9	1.1 1.3	2.8 3.4	ns
t _{PZH} t _{PZL}	Output enable time to High and Low level	2	1.6 2.3	2.7 3.5	3.7 4.0	1.6 2.3	4.5 4.8	ns
t _{PHZ}	Output disable time from High and Low level	2	2.0 1.6	3.0 2.4	4.0 3.2	2.0 1.6	4.6 4.1	ns

AC WAVEFORMS

 $V_M = 1.5V$, $V_{IN} = GND$ to 3.0V



Waveform 1. Input (An) to Output (Yn) Propagation Delays



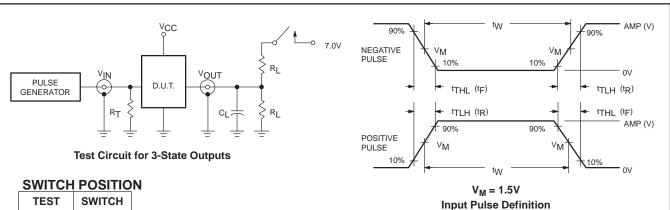
Waveform 2. 3-State Output Enable and Disable Times

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16-bit buffer/line driver (3-State)

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TEST CIRCUIT AND WAVEFORMS



TEST	SWITCH
t _{PLZ}	closed
t_{PZL}	closed
All other	open

DEFINITIONS

R_L = Load resistor; see AC CHARACTERISTICS for value.

 $C_L = Load$ capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

$$\begin{split} R_T = & \text{ Termination resistance should be equal to } Z_{OUT} \text{ of } \\ & \text{ pulse generators.} \end{split}$$

FAMILY	INPUT PULSE REQUIREMENTS						
FAMILI	Amplitude	Rep. Rate	t _W	t _R	t _F		
74ABT/H16	3.0V	1MHz	500ns	2.5ns	2.5ns		

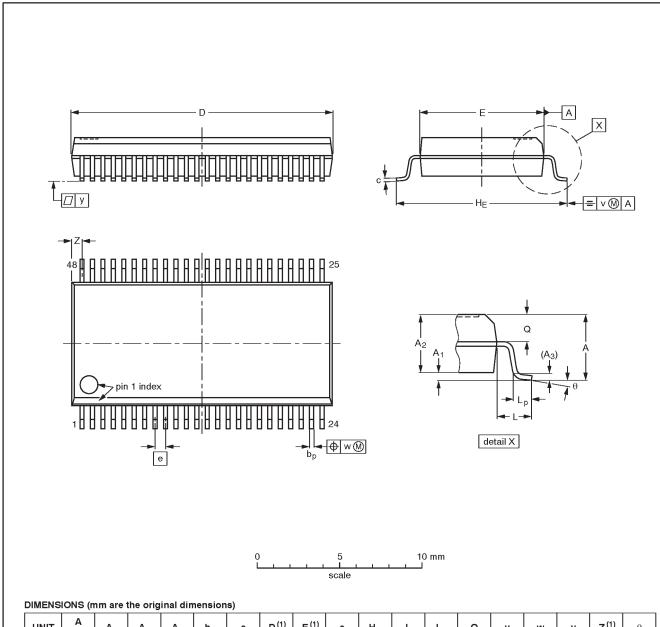
SA00018

16-bit buffer/line driver (3-State)

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SSOP48: plastic shrink small outline package; 48 leads; body width 7.5 mm

SOT370-1



UNIT	A max.	Α1	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2.8	0.4 0.2	2.35 2.20	0.25	0.3 0.2	0.22 0.13	16.00 15.75	7.6 7.4	0.635	10.4 10.1	1.4	1.0 0.6	1.2 1.0	0.25	0.18	0.1	0.85 0.40	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

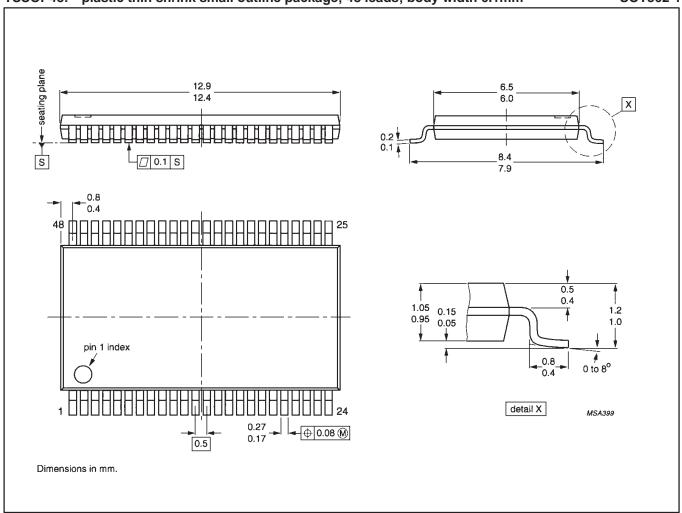
OUTLINE		REFER	RENCES	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT370-1		MO-118AA			93-11-02 95-02-04

16-bit buffer/line driver (3-State)

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TSSOP48: plastic thin shrink small outline package; 48 leads; body width 6.1mm

SOT362-1



16-bit buffer/line driver (3-State)

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Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
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^[1] Please consult the most recently issued datasheet before initiating or completing a design.

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